



WIDEBAND LNA MODULE, 7 - 17 GHz

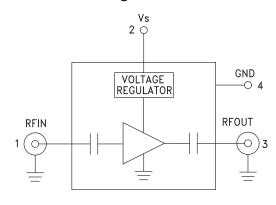


Typical Applications

The HMC-C016 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

Noise Figure: 2 dB @ 16 GHz

Gain: 22 dB

P1dB Output Power: +14 dBm @ 16 GHz

50 Ohm Matched Input/Output

Regulated Supply

Hermetically Sealed Module

Field Replaceable SMA Connectors

-55 to +85°C Operating Temperature

General Description

The HMC-C016 is a GaAs MMIC PHEMT Low Noise Amplifier in a miniature, hermetic module which operates between 7 and 17 GHz. This high dynamic range amplifier provides 22 dB of gain, 2 dB noise figure and up to +14 dBm of output power at 1 dB gain compression while operating from a single positive supply between +8 and +16 volts. The I/Os are internally matched to 50 Ohms and internally DC blocked for robust performance. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vs = +8V to +16V

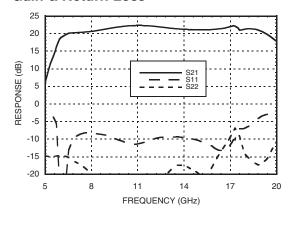
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	7 - 9		9 - 13			13 - 17			GHz	
Gain	17.5	20.5		19	22		18	21		dB
Gain Variation Over Temperature		0.02	0.025		0.02	0.025		0.02	0.025	dB/ °C
Noise Figure		3	4.5		2.5	3		2	3.0	dB
Input Return Loss		8			10			10		dB
Output Return Loss		20			25			15		dB
Output Power for 1 dB Compression (P1dB)	8	12		11	14		11	14		dBm
Saturated Output Power (Psat)		17			18			18		dBm
Output Third Order Intercept (IP3)		24			25			25		dBm
Supply Current		93			93			93		mA



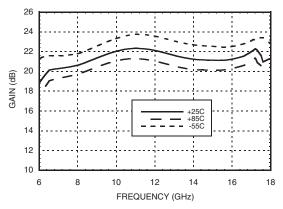


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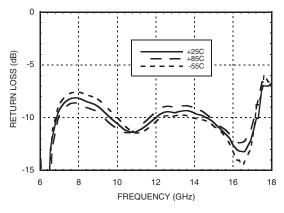
Gain & Return Loss



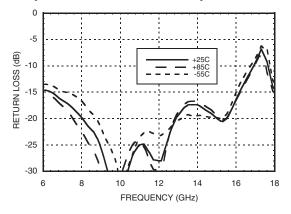
Gain vs. Temperature



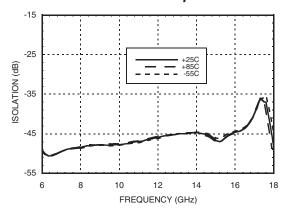
Input Return Loss vs. Temperature



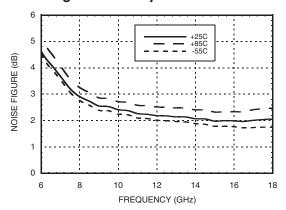
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature

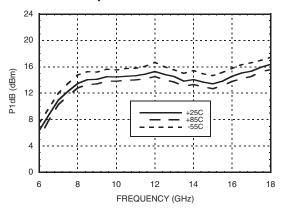




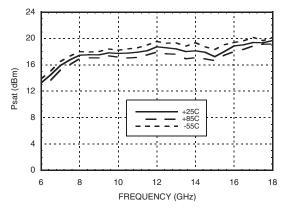


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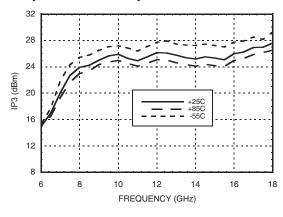
P1dB vs. Temperature



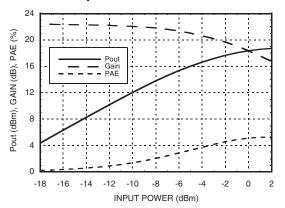
Psat vs. Temperature



Output IP3 vs. Temperature



Power Compression @ 12 GHz



Absolute Maximum Ratings

Bias Supply Voltage (Vs)	-0.3 Vdc to +25 Vdc		
RF Input Power (RFIN)	+10 dBm		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-55 to +85 °C		







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Pin Descriptions

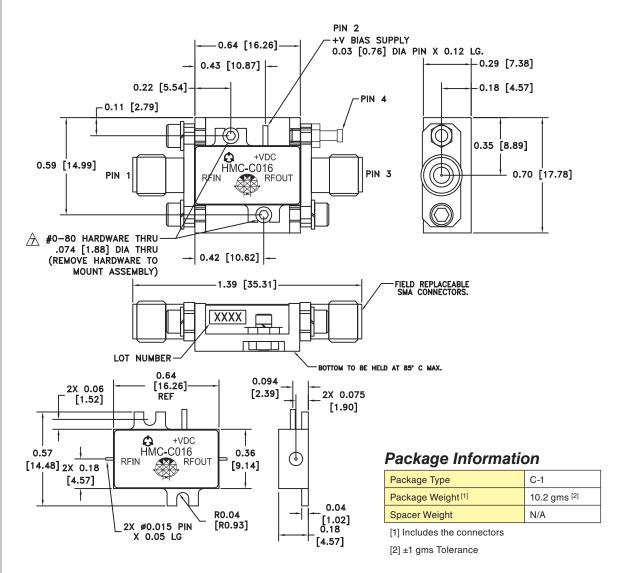
Pin Number	Function	Description	Interface Schematic		
1	RFIN & RF Ground	RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO— -		
2	Vs	Power supply voltage for the amplifier.	VS VOLTAGE REGULATOR		
3	RFOUT & RF Ground	RF output connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ I → RFOUT		
4	GND	Power supply ground.	⊖ GND		





WIDEBAND LNA MODULE, 7 - 17 GHz

Outline Drawing



NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR $^{\text{TM}}$
- 2. SPACER MATERIAL: ALUMINUM
- 3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
- 4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
- 6. FIELD REPLACEABLE SMA CONNECTORS.
 - TENSOLITE 5602 5CCSF OR EQUIVALENT.
- TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 -80 HARDWARE WITH DESIRED MOUNTING SCREWS.



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CONNECTORIZED MODULES - AMPLIFIERS



ANALOGDEVICES

Notes:

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